

Transistor, NPN TO-3

multicompPRO



Description:

High voltage power transistor.

Designed for use in high-voltage, high-speed, power switching in inductive circuit, motor control, solenoid and relay drivers.

Features:

- Collector-emitter sustaining voltage - $V_{CEO(sus)} = 4,000V$ (Min.)
- Low collector-emitter saturation voltage - $V_{CE(sat)} = 3V$ (Max.) at $I_C = 8A$, $I_B = 2.5A$

Maximum Ratings

Characteristic	Symbol	BUX80	Unit
Collector-Emitter Voltage	V_{CEO}	400	V
Collector-Emitter Voltage ($V_{BE} = 0$)	V_{CES}	800	
Emitter-Base Voltage	V_{EBO}	10	
Collector Current - Continuous -Peak	I_C	10 15	A
Base Current-Continuous	I_B	5	
Total Power Dissipation at $T_C = 25^\circ C$ Derate above $25^\circ C$	P_D	100 0.8	W W/ $^\circ C$
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +200	$^\circ C$

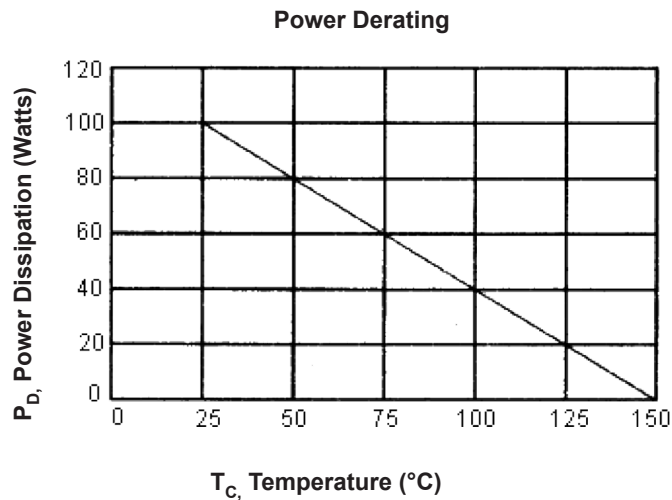
Thermal Characteristics

Characteristics	Symbol	Max.	Unit
Thermal Resistance Junction to Case	$R_{\theta JC}$	1.25	$^\circ C/W$

Transistor, NPN

TO-3

multicompPRO



Electrical Characteristics (TC = 25°C unless otherwise noted)

Characteristic	Symbol	Min.	Max.	Unit
----------------	--------	------	------	------

Off Characteristics

Collector-Emitter Sustaining Voltage (1) ($I_C = 100\text{mA}$, $I_B = 0$, $L = 25\text{mH}$)	V	400	-	V
Collector Cut off Current ($V_{CE} = 800\text{V}$, $V_{BE} = 0$) ($V_{CE} = 800\text{V}$, $V_{BE} = 0$, $T_C = 125^\circ\text{C}$)	I_{CES}	-	1 3	mA
Emitter Cut off Current ($V_{EB} = 10\text{V}$, $I_C = 0$)	I_{EBO}	-	10	

On Characteristics (1)

DC Current Gain ($I_C = 1.2\text{A}$, $V_{CE} = 5\text{V}$)	h	30 (typical)	-	-
Collector-Emitter Saturation Voltage ($I_C = 5\text{A}$, $I_B = 1\text{mA}$) ($I_C = 8\text{A}$, $I_B = 2.5\text{mA}$)	$V_{CE(sat)}$	-	1.5 3	V
Base-Emitter Saturation Voltage ($I_C = 5.0\text{A}$, $I_B = 1\text{mA}$) ($I_C = 8.0\text{A}$, $I_B = 2.5\text{mA}$)	$V_{BE(sat)}$	-	1.4 1.8	

Switching Characteristics

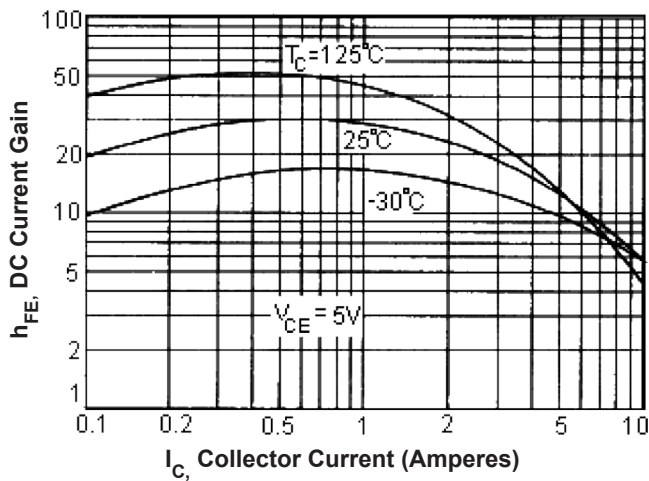
Turn On Time	$V_{CC} = 250\text{V}$, $I_C = 5\text{A}$	t_{on}	-	0.5	μs
Storage Time	$I_{B1} = 1\text{A}$, $I_{B2} = -2\text{A}$	t_s	-	3.5	
Fall Time	-	t_f	-	0.5	

(1) Pulse Test : Pulse Width = 300 μs , Duty Cycle $\leq 2\%$.

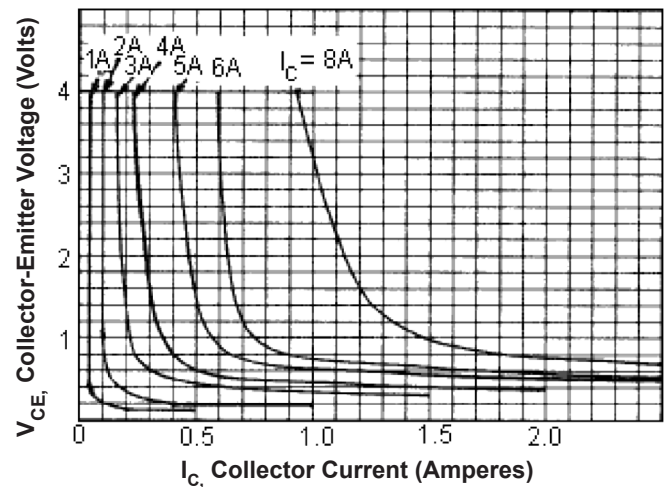
Transistor, NPN TO-3

multicompPRO

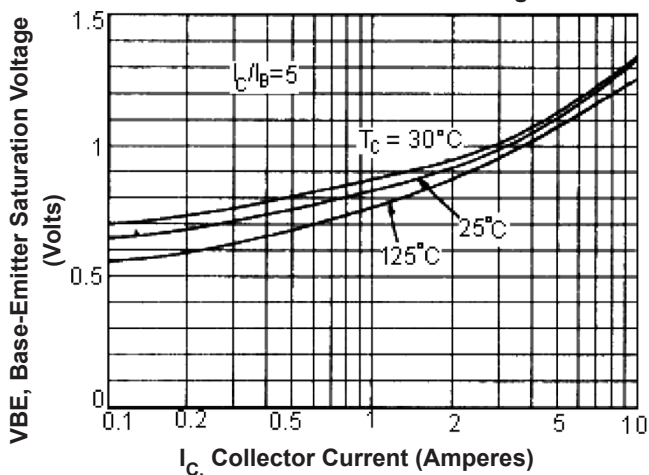
DC Current Gain



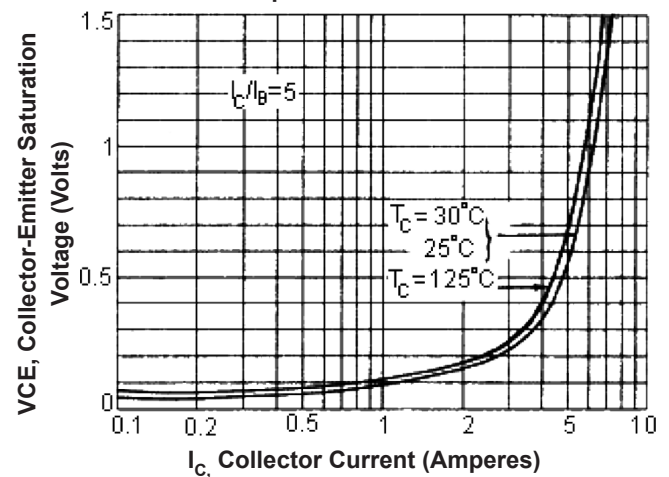
Collector Saturation Region



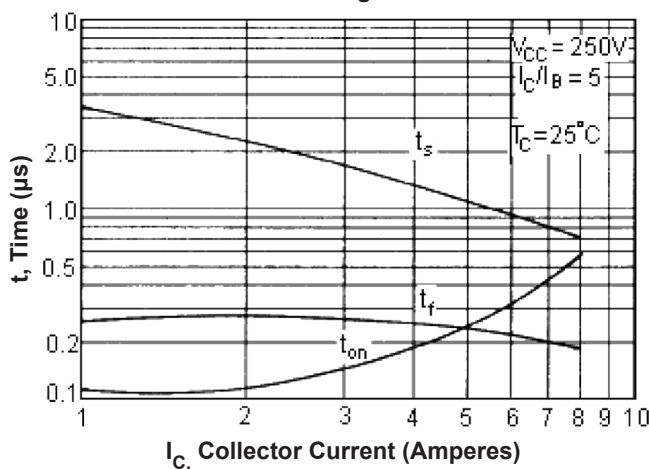
Base-Emmitter Saturation Voltage



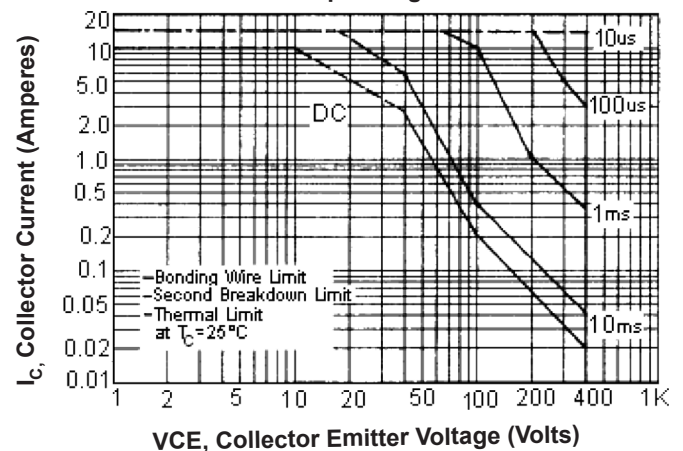
Temperature Coefficients



Switching Time



Safe Operating Area



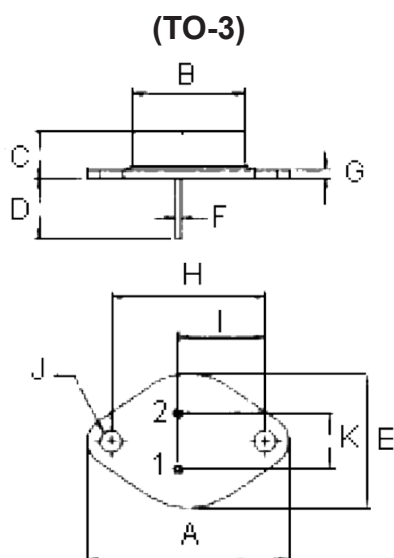
Newark.com/multicomp-pro
Farnell.com/multicomp-pro
Element14.com/multicomp-pro

multicompPRO

Transistor, NPN TO-3

multicompPRO

Dimensions



Dim.	Min.	Max.
A	38.75	39.96
B	19.28	22.23
C	7.96	9.28
D	11.18	12.19
E	25.2	26.67
F	0.92	1.09
G	1.38	1.62
H	29.9	30.4
I	16.64	17.3
J	3.88	4.36
K	10.67	11.18

Dimensions : (Millimetres)

Pin Configuration

- Pin 1. Base
2. Emitter
Collector (Case)

Part Number Table

Description	Part Number
Transistor, NPN, TO-3	BUX80

Important Notice : This data sheet and its contents (the "Information") belong to the members of the AVNET group of companies (the "Group") or are licensed to it. No licence is granted for the use of it other than for information purposes in connection with the products to which it relates. No licence of any intellectual property rights is granted. The Information is subject to change without notice and replaces all data sheets previously supplied. The Information supplied is believed to be accurate but the Group assumes no responsibility for its accuracy or completeness, any error in or omission from it or for any use made of it. Users of this data sheet should check for themselves the Information and the suitability of the products for their purpose and not make any assumptions based on information included or omitted. Liability for loss or damage resulting from any reliance on the Information or use of it (including liability resulting from negligence or where the Group was aware of the possibility of such loss or damage arising) is excluded. This will not operate to limit or restrict the Group's liability for death or personal injury resulting from its negligence. Multicomp Pro is the registered trademark of Premier Farnell Limited 2019.

Newark.com/multicomp-pro
Farnell.com/multicomp-pro
Element14.com/multicomp-pro

multicompPRO